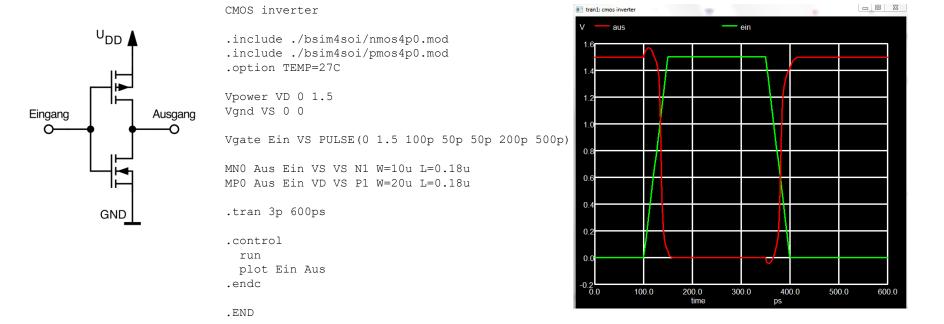
ngspice, development update and electrothermal simulation

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ngspice – what is it?

Circuit simulator that numerically solves equations describing (electronic) circuits made of passive and active devices for (time varying) currents and voltages

Open source successor of venerable spice3f5 from Berkeley



the circuit the input

the output

The two major application areas

PCB design support

Circuits are made with a mix of ICs and discrete components

Requirements:

Comfortable user interface (offered by third parties)

PSPICE and LTSPICE model compatibility

IC design support

Circuits are made of (MOS) transistors and (parasitic) passive components

Requirements:

BSIM 3, 4, (BULK) models etc.

Large circuit capability, speed

HSPICE PDK compatibility

KiCad, Eagle, PartSim, CoolCAD, PSIM, WeSpice ... gEDA, Yosys, efabless, Isotel, XSCHEM, PySpice ...

Towards ngspice-32 (03/2020)

Improved graphics

Text orientation, fonts, color, linewidth selections

Monte Carlo

Improved statistical IC analysis

UNICODE support

utf-8 and wide-char for strings:

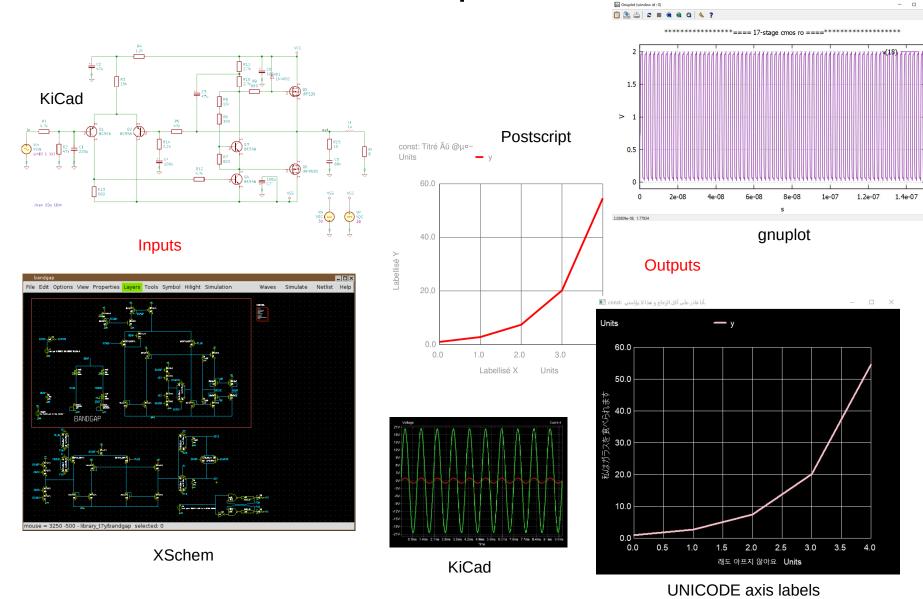
Text in plots, node names, file and directory names

Revised VDMOS model

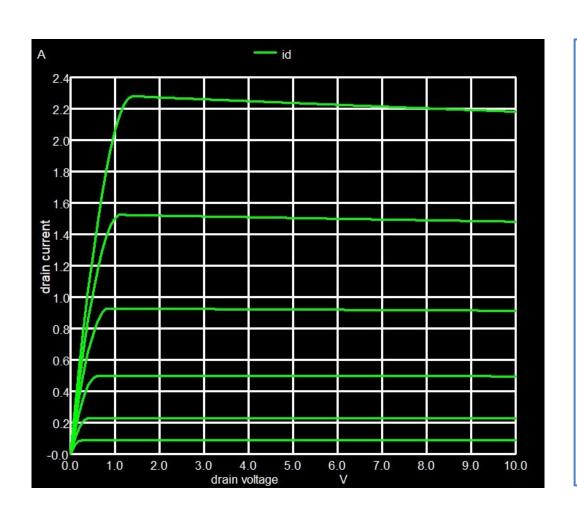
efficient model for power MOS transistors, now includes self heating (electrothermal model)

In addition: major code cleanup, enhanced robustness against buggy input, improved error handling, improved convergence

Some impressions



Temperature influence on devices



Power MOS

Drain voltage is rising, current is decreasing?

=> Temperature effect!

Electric power => heat

=> temperature

Mobility is decreasing with temperature.

=> How to model this effect?

Electro-thermal modelling

Make use of the equivalence of electronic and thermal properties (circuits).

Translate thermal to electrical circuits, run both circuit parts in ngspice. Electrical power dissipation generates heat, restricted heat flow rises temperature, temperature changes power disspation.

	Thermal term	Electrical term
Capacitance	c [J/K]	C [A/V]
Conductance	g [W/K]	1/R [1/Ω]
Temeprature/Voltage	<i>T(t)</i> [K]	<i>V(t)</i> [V]
Heat/Current	Q [W]	<i>I(t)</i> [A]
Time constant	c/g [s]	RC [s]

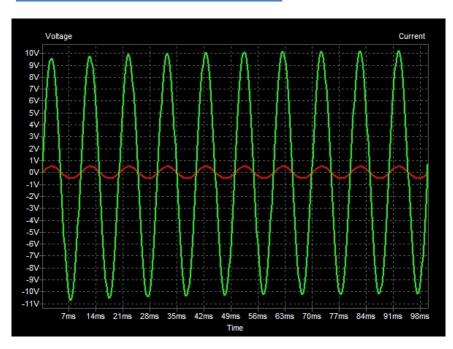
Example: Amp with power MOS

http://www.tubecad.com/2009/08/blog0168.htm R9 1G Tj1 Ci Junction temperatures VCC U1A 16 IPP083N10N5 TL072 0.33u Tj2 R16 GND (Tcase1 R10 R11 100 GND 0.2 3 Tcase1 R1 390k C4 100k 300m Vin1 10 m Vamb1 VDC R5 R7 Heat sinks dc 0 ac 1 sin(0 0.5 100) 19.5k 0.1 GND (out R13 R14 0.2 **C**5 R15 U1B IPP083N10N5 Tcase2 1u _ 1k TL072 GND R17 Tcase2 300m 100 GND VCC VCC GND R6 100k 00 thermal circuit 1u 4 10k ± U1€ V1 VDC 1k 0.8 J TL072 Loudspeaker Rt1 GND 8 GND GND GND GND GND GND

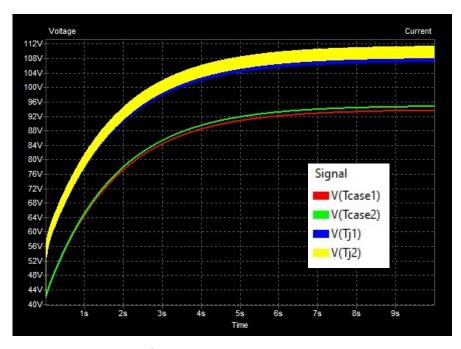
electric circuit

Amplifier electro-thermal simulation results

Integrated signal and temperature simulation



Amplifier input and output voltages. Simulated for 100 ms at 42 °C (similar curve results at 108 °C)



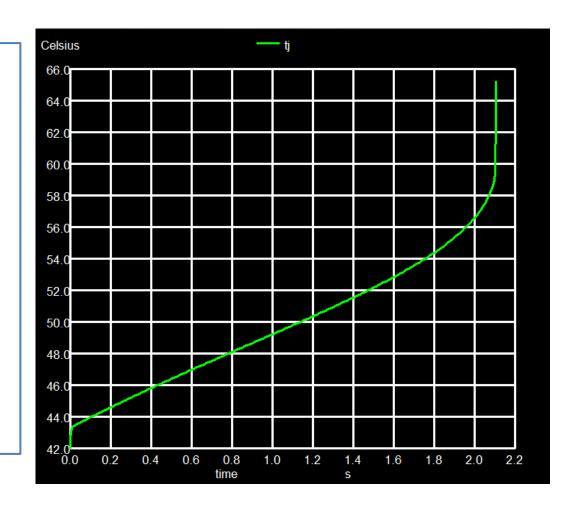
Transistor case and transistor junction temperatures. Simulated for 10 s with Tj rising from 42 to 108 °C

Modelling of thermal runaway

Resistor with negative temperature coefficient 1 Ω , 1 V, -0.03 Ω /K

After some time the temperature rises beyond bounds

=> thermal runaway device destruction



Summary

Ngspice-32 will be available in March 2020 with several new features:

- Many bug fixes and improved error messages
- Electro-thermal simulation with VDMOS Power MOS model
- UNICODE compatibility
- Enhanced Monte Carlo simulation capability

And even then: Still a lot to do for ngspice-33...